



# PJS6401

## 30V P-Channel Enhancement Mode MOSFET

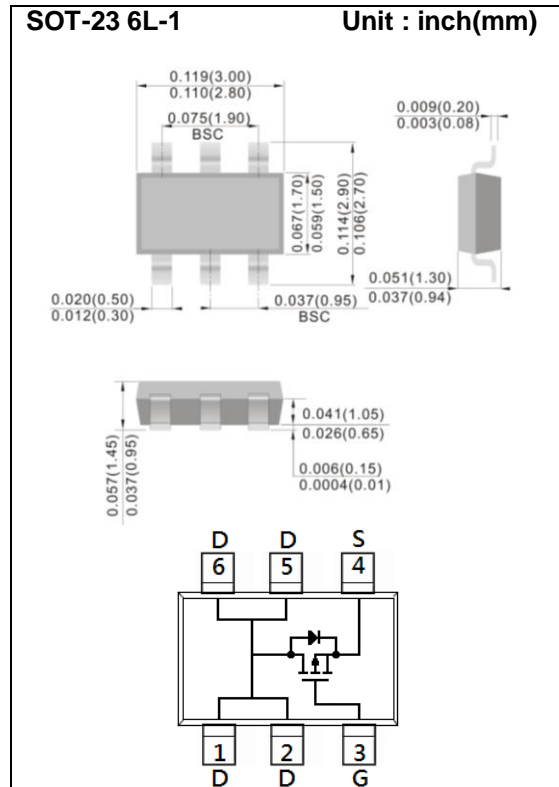
**Voltage**    **-30 V**    **Current**    **-4.6A**

### Features

- $R_{DS(ON)}$  ,  $V_{GS}@-10V$ ,  $I_D@-4.6A < 71m\Omega$
- $R_{DS(ON)}$  ,  $V_{GS}@-4.5V$ ,  $I_D@-3.3A < 81m\Omega$
- $R_{DS(ON)}$  ,  $V_{GS}@-2.5V$ ,  $I_D@-1.8A < 110m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

### Mechanical Data

- Case: SOT-23 6L-1 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.014 grams
- Marking: S01



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Continuous Drain Current	$I_D$	-4.6	A
Pulsed Drain Current	$I_{DM}$	-18.4	A
Power Dissipation	$P_D$	$T_a=25^\circ C$	2
		Derate above $25^\circ C$	16
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~150	$^\circ C$
Typical Thermal resistance	$R_{\theta JA}$	62.5	$^\circ C/W$
- Junction to Ambient <sup>(Note 3)</sup>			



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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.5	-0.96	-1.3	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-4.6A$	-	60	71	m $\Omega$
		$V_{GS}=-4.5V, I_D=-3.3A$	-	67	81	
		$V_{GS}=-2.5V, I_D=-1.8A$	-	84	110	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-30V, V_{GS}=0V$	-	-0.01	-1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$	-	$\pm 10$	$\pm 100$	nA
<b>Dynamic</b>						
Total Gate Charge	$Q_g$	$V_{DS}=-15V, I_D=-4.6A,$ $V_{GS}=-10V$ (Note 1,2)	-	15.5	-	nC
Gate-Source Charge	$Q_{gs}$		-	1.5	-	
Gate-Drain Charge	$Q_{gd}$		-	2.2	-	
Input Capacitance	$C_{iss}$	$V_{DS}=-15V, V_{GS}=0V,$ $f=1.0MHz$	-	637	-	pF
Output Capacitance	$C_{oss}$		-	50	-	
Reverse Transfer Capacitance	$C_{rss}$		-	35	-	
<b>Switching</b>						
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-15V, I_D=-4.6A,$ $V_{GS}=-10V,$ $R_G=6\Omega$ (Note 1,2)	-	3	-	ns
Turn-On Rise Time	$t_r$		-	43	-	
Turn-Off Delay Time	$t_{d(off)}$		-	224	-	
Turn-Off Fall Time	$t_f$		-	101	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	-2.0	A
Diode Forward Voltage	$V_{SD}$	$I_S=-1.0A, V_{GS}=0V$		-0.75	-1.2	V

NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
4. The maximum current rating is package limited



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## TYPICAL CHARACTERISTIC CURVES

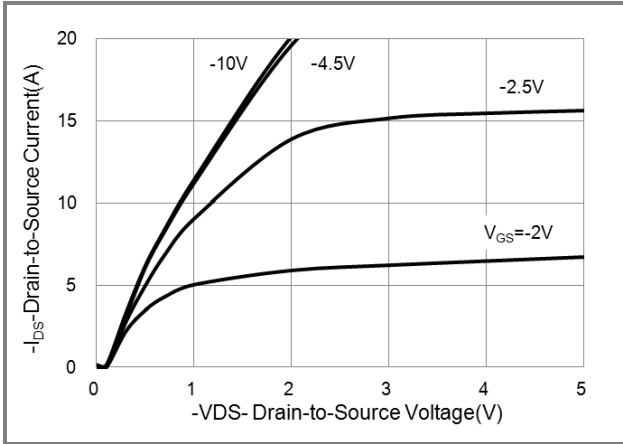


Fig.1 On-Region Characteristics

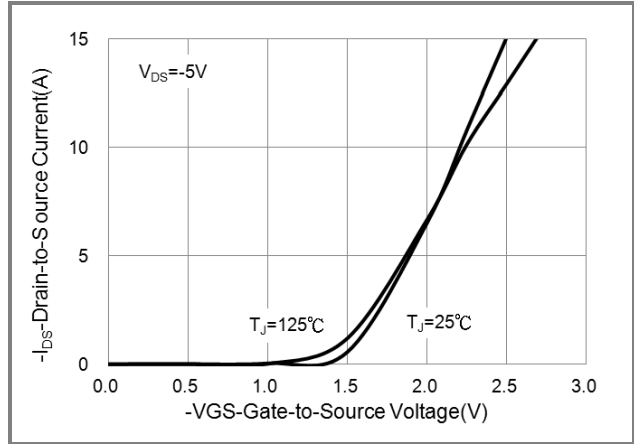


Fig.2 Transfer Characteristics

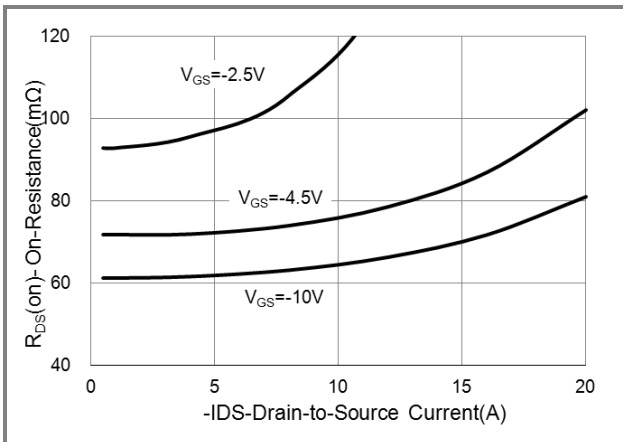


Fig.3 On-Resistance vs. Drain Current

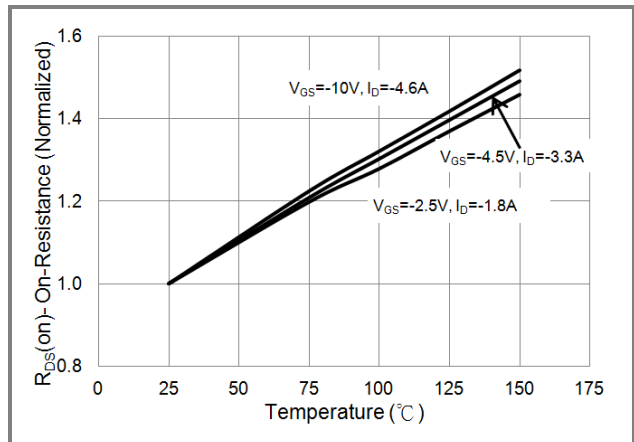


Fig.4 On-Resistance vs. Junction temperature

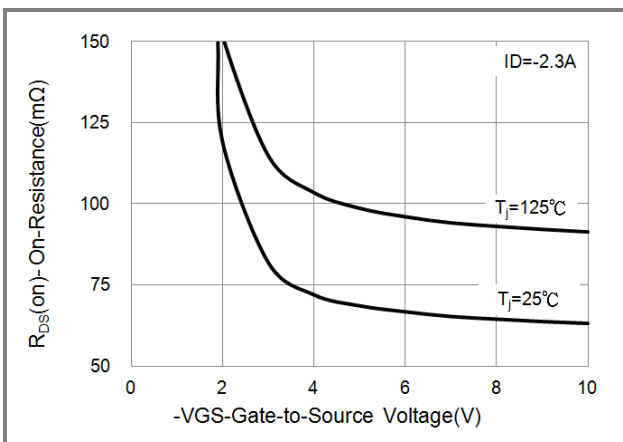


Fig.5 On-Resistance Variation with VGS.

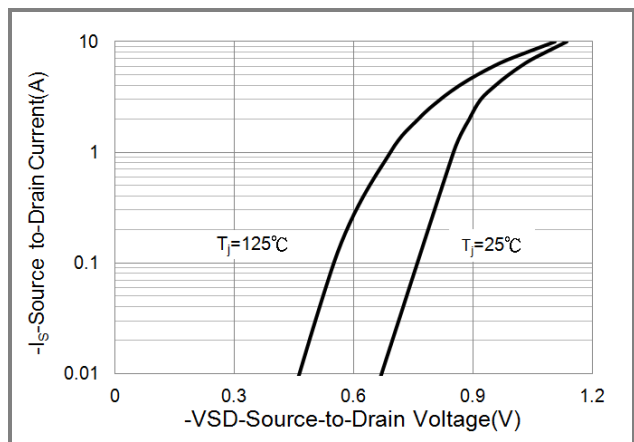


Fig.6 Body Diode Characteristics



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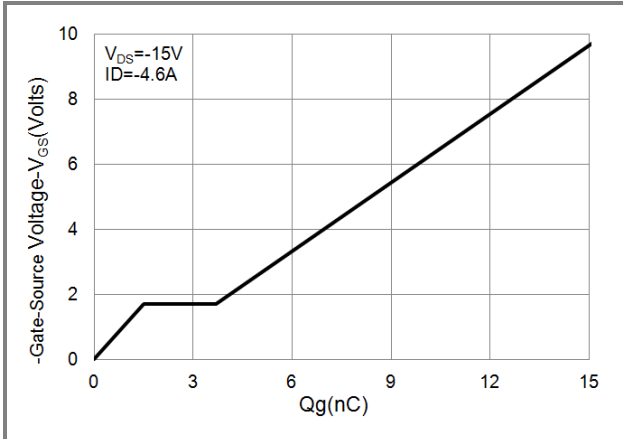


Fig.7 Gate-Charge Characteristics

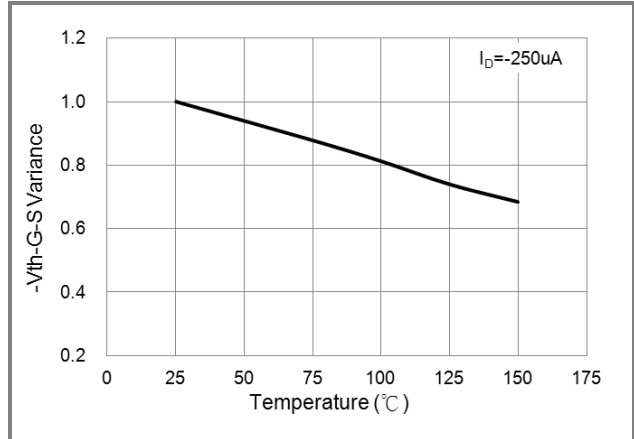


Fig.8 Threshold Voltage Variation with Temperature.

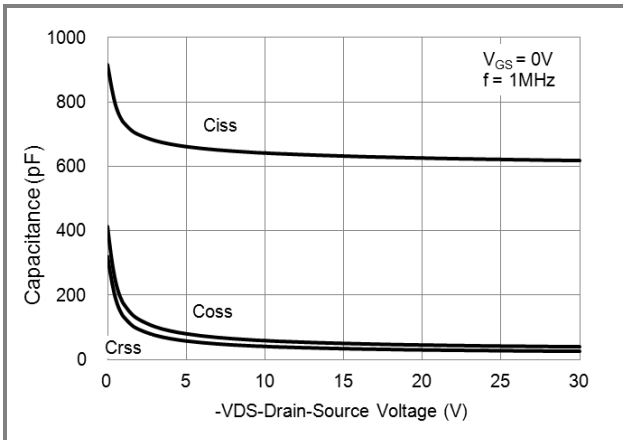


Fig.9 Capacitance vs. Drain-Source Voltage.

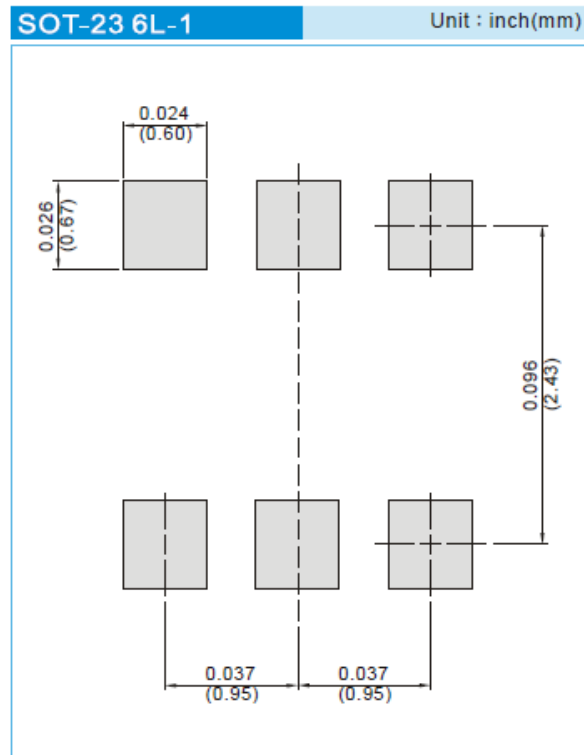


# PJS6401

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJS6401_S1_00001	SOT-23 6L-1	3K pcs / 7" reel	S01	Halogen free

## MOUNTING PAD LAYOUT





## PJS6401

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